

- **EPIC™** (Enhanced-Performance Implanted CMOS) Submicron Process
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **Typical  $V_{OLP}$  (Output Ground Bounce) < 0.8 V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$**
- **Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot) > 2 V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$**
- **Inputs Accept Voltages to 5.5 V**
- **Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), Ceramic Flat (W) Package, and DIPs (J)**

## description

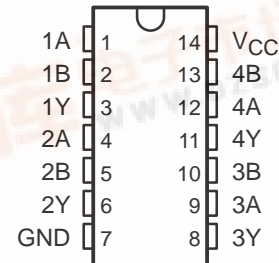
The SN54LVC00A quadruple 2-input positive-NAND gate is designed for 2.7-V to 3.6-V  $V_{CC}$  operation and the SN74LVC00A quadruple 2-input positive-NAND gate is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

The 'LVC00A devices perform the Boolean function  $Y = \overline{A \bullet B}$  or  $Y = \overline{A + B}$  in positive logic.

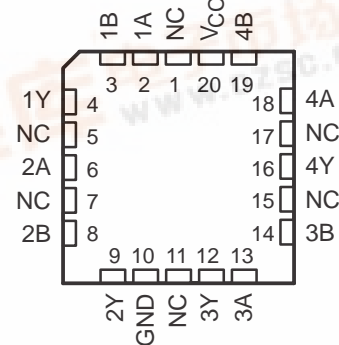
Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

The SN54LVC00A is characterized for operation over the full military temperature range of  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ . The SN74LVC00A is characterized for operation from  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .

SN54LVC00A ... J OR W PACKAGE  
 SN74LVC00A ... D, DB, OR PW PACKAGE  
 (TOP VIEW)



SN54LVC00A ... FK PACKAGE  
 (TOP VIEW)



NC – No internal connection

FUNCTION TABLE  
 (each gate)

INPUTS		OUTPUT Y
A	B	
H	H	L
L	X	H
X	L	H

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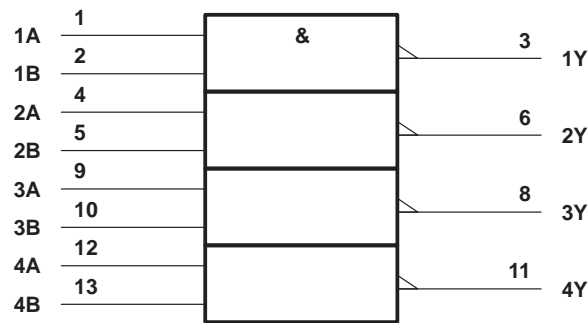


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 On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

SN54LVC00A, SN74LVC00A  
QUADRUPLE 2-INPUT POSITIVE-NAND GATES

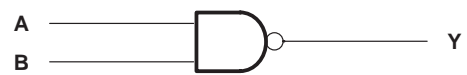
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logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.  
Pin numbers shown are for the D, DB, J, PW, and W packages.

logic diagram, each gate (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, $V_{CC}$	–0.5 V to 6.5 V
Input voltage range, $V_I$ (see Note 1)	–0.5 V to 6.5 V
Output voltage range, $V_O$ (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ )	–50 mA
Continuous output current, $I_O$	±50 mA
Continuous current through $V_{CC}$ or GND	±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3):	
D package	127°C/W
DB package	158°C/W
PW package	170°C/W
Storage temperature range, $T_{stg}$	–65°C to 150°C

‡ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
  2. The value of  $V_{CC}$  is provided in the recommended operating conditions table.
  3. The package thermal impedance is calculated in accordance with JESD 51.

# SN54LVC00A, SN74LVC00A QUADRUPL 2-INPUT POSITIVE-NAND GATES

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## recommended operating conditions (see Note 4)

			SN54LVC00A		SN74LVC00A		UNIT
			MIN	MAX	MIN	MAX	
V <sub>CC</sub>	Supply voltage	Operating	2	3.6	1.65	3.6	V
		Data retention only	1.5		1.5		
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V			0.65×V <sub>CC</sub>		V
		V <sub>CC</sub> = 2.3 V to 2.7 V			1.7		
		V <sub>CC</sub> = 2.7 V to 3.6 V	2		2		
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V			0.35×V <sub>CC</sub>		V
		V <sub>CC</sub> = 2.3 V to 2.7 V			0.7		
		V <sub>CC</sub> = 2.7 V to 3.6 V	0.8		0.8		
V <sub>I</sub>	Input voltage		0	5.5	0	5.5	V
V <sub>O</sub>	Output voltage		0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 1.65 V			−4		mA
		V <sub>CC</sub> = 2.3 V			−8		
		V <sub>CC</sub> = 2.7 V	−12		−12		
		V <sub>CC</sub> = 3 V	−24		−24		
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65 V			4		mA
		V <sub>CC</sub> = 2.3 V			8		
		V <sub>CC</sub> = 2.7 V	12		12		
		V <sub>CC</sub> = 3 V	24		24		
T <sub>A</sub>	Operating free-air temperature		−55	125	−40	85	°C

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# SN54LVC00A, SN74LVC00A

## QUADRUPLE 2-INPUT POSITIVE-NAND GATES

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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	SN54LVC00A			SN74LVC00A			UNIT
			MIN	TYP†	MAX	MIN	TYP†	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = −100 μA	1.65 V to 3.6 V				V <sub>CC</sub> −0.2			V
		2.7 V to 3.6 V	V <sub>CC</sub> −0.2						
	I <sub>OH</sub> = −4 mA	1.65 V				1.2			
	I <sub>OH</sub> = −8 mA	2.3 V				1.7			
	I <sub>OH</sub> = −12 mA	2.7 V		2.2		2.2			
		3 V		2.4		2.4			
	I <sub>OH</sub> = −24 mA	3 V		2.2		2.2			
V <sub>OL</sub>	I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V				0.2			V
		2.7 V to 3.6 V	0.2						
	I <sub>OL</sub> = 4 mA	1.65 V				0.45			
	I <sub>OL</sub> = 8 mA	2.3 V				0.7			
	I <sub>OL</sub> = 12 mA	2.7 V		0.4		0.4			
	I <sub>OL</sub> = 24 mA	3 V		0.55		0.55			
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	3.6 V	±5			±5			μA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	3.6 V	10			10			μA
ΔI <sub>CC</sub>	One input at V <sub>CC</sub> − 0.6 V, Other inputs at V <sub>CC</sub> or GND	2.7 V to 3.6 V	500			500			μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V	5			5			pF

† All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVC00A				UNIT
			V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		
			MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	5.1		1	4.3	ns

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN74LVC00A								UNIT
			V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	‡	‡	‡	‡	5.1	1	4.3	ns	
t <sub>sk(o)</sub> <sup>§</sup>								1		ns	

‡ This information was not available at the time of publication.

§ Skew between any two outputs of the same package switching in the same direction

# SN54LVC00A, SN74LVC00A QUADRUPLE 2-INPUT POSITIVE-NAND GATES

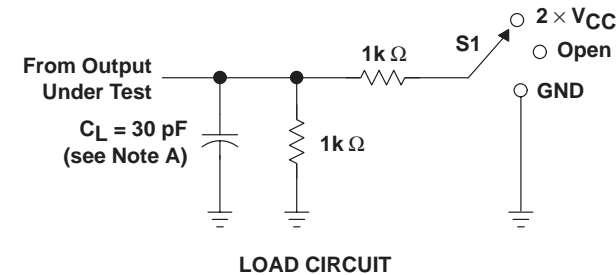
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operating characteristics,  $T_A = 25^\circ\text{C}$

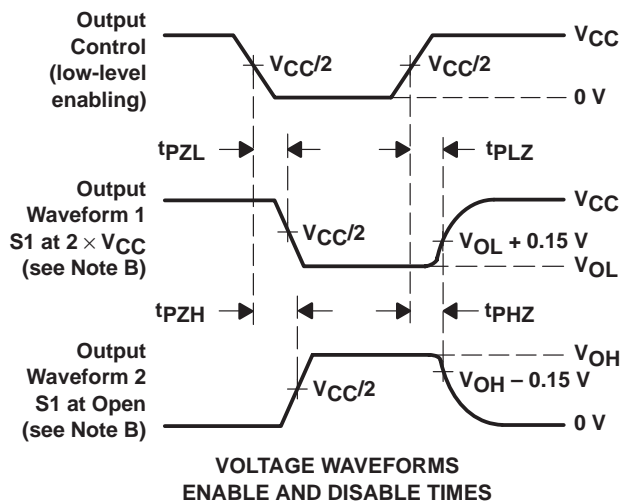
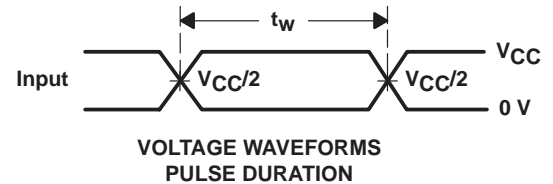
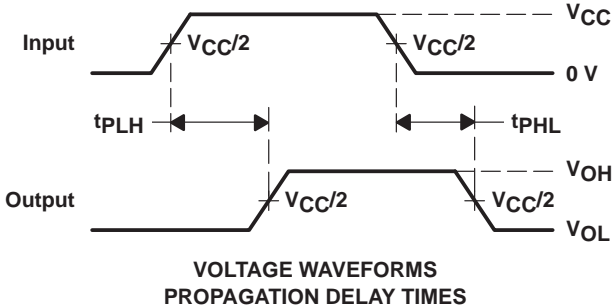
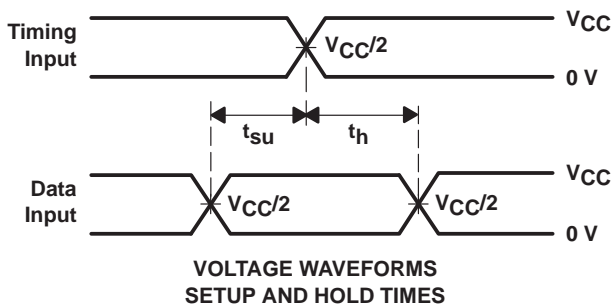
PARAMETER	TEST CONDITIONS	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$	$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$	$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$	UNIT
		TYP	TYP	TYP	
$C_{pd}$ Power dissipation capacitance per gate	$f = 10\text{ MHz}$	†	†	9.5	pF

† This information was not available at the time of publication.

## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$



TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	$2 \times V_{CC}$
$t_{PHZ}/t_{PHL}$	Open



- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\text{ }\Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

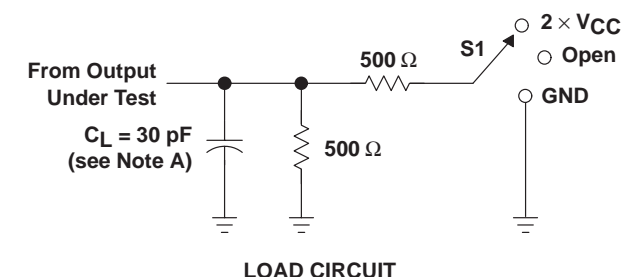
Figure 1. Load Circuit and Voltage Waveforms

# SN54LVC00A, SN74LVC00A QUADRUPLE 2-INPUT POSITIVE-NAND GATES

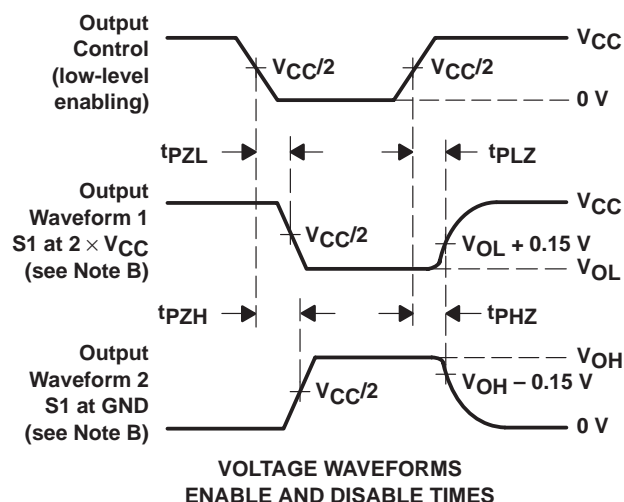
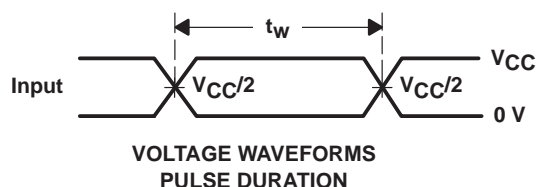
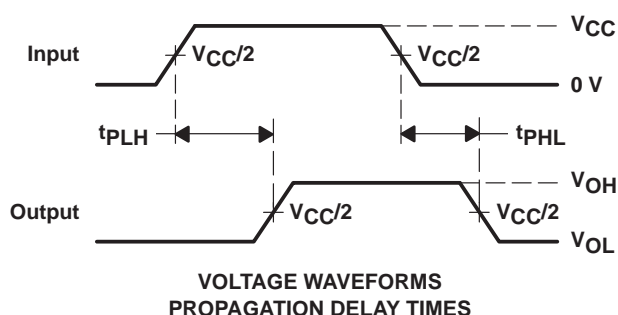
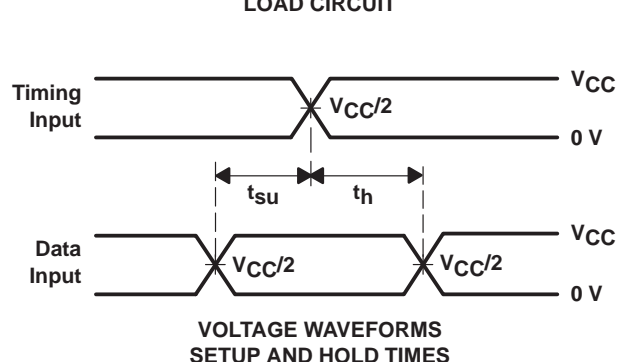
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## PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$$



TEST	S1
$t_{pd}$ $t_{PLZ}/t_{PZL}$ $t_{PHZ}/t_{PZH}$	Open 2 $\times V_{CC}$ GND



- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2 \text{ ns}$ ,  $t_f \leq 2 \text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

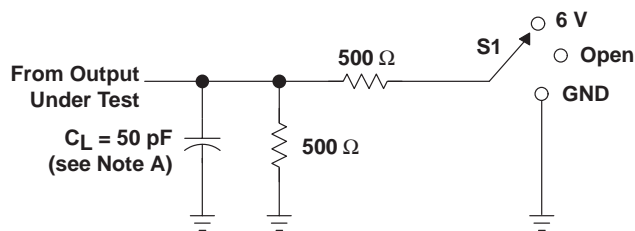
Figure 2. Load Circuit and Voltage Waveforms

# SN54LVC00A, SN74LVC00A QUADRUPL 2-INPUT POSITIVE-NAND GATES

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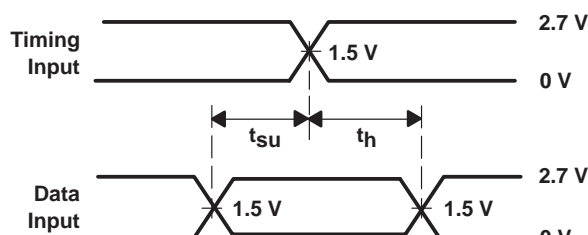
## PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7 \text{ V AND } 3.3 \text{ V} \pm 0.3 \text{ V}$

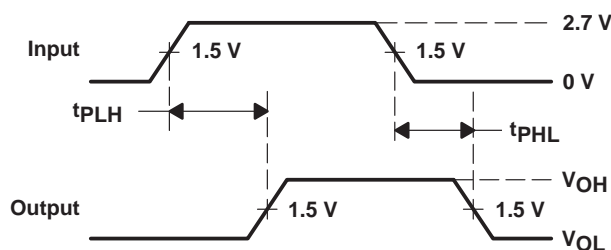


LOAD CIRCUIT

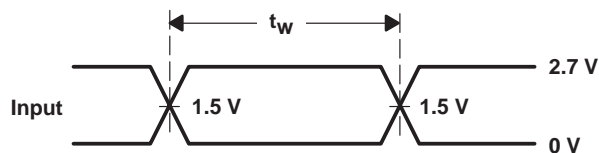
TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	6 V
$t_{PHZ}/t_{PZH}$	GND



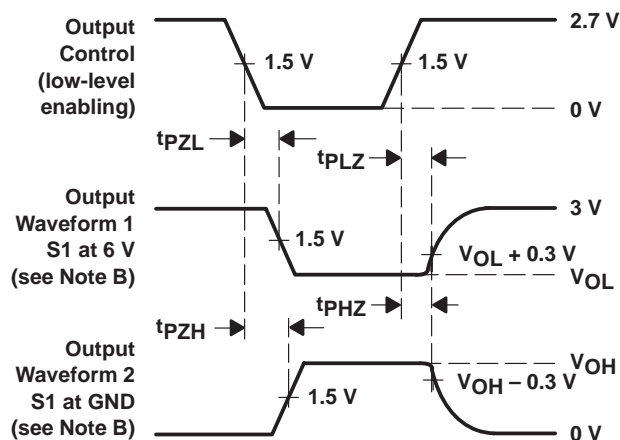
VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES

- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2.5 \text{ ns}$ ,  $t_f \leq 2.5 \text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 3. Load Circuit and Voltage Waveforms

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